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查询LM7001供应商

#### Ordering number : EN5262

NMOS LSI

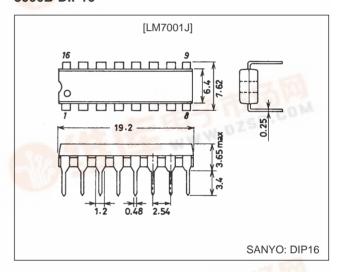
SANYO Direct PLL Frequency Synthesizers for Electronic Tuning

# **Features**

- The LM7001J and LM7001JM are PLL frequency synthesizer LSIs for tuners, making it possible to make up high-performance AM/FM tuners easily.
- These LSIs are software compatible with the LM7000, but do not include an IF calculation circuit.
- The FM VCO circuit includes a high-speed programmable divider that can divide directly.
- Seven reference frequencies: 1, 5, 9, 10, 25, 50, and 100 kHz
- Band-switching outputs (3 bits)
- Controller clock output (400 kHz)
- Clock time base output (8 Hz)
- Serial input circuit for data input (using the CE, CL, and DATA pins)

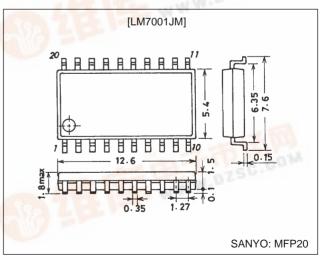
# Package Dimensions

unit: mm 3006B-DIP16

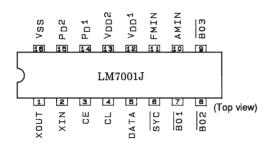


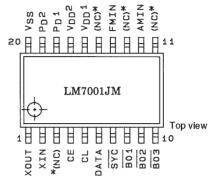
unit: mm

### 3036B-MFP20



# **Pin Assignments**





Note: \* NC pins must be left open.

# Specifications

# Absolute Maximum Ratings at Ta = 25°C, $V_{SS}$ = 0 V

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>DD</sub> max	V <sub>DD</sub> 1, V <sub>DD</sub> 2	-0.3 to +7.0	V
Maximum input voltage	V <sub>IN</sub> 1 max	CE, CL, DATA	-0.3 to +7.0	V
	V <sub>IN</sub> 2 max	Input pins other than V <sub>IN</sub> 1	-0.3 to V <sub>DD</sub> + 0.3	V
Maximum output voltage	V <sub>OUT</sub> 1 max	SYC	-0.3 to +7.0	V
	V <sub>OUT</sub> 2 max	BO1 to BO3	-0.3 to +13	V
	V <sub>OUT</sub> 3 max	Output pins other than $V_{OUT}$ 1 and $V_{OUT}$ 2	-0.3 to V <sub>DD</sub> + 0.3	V
Maximum output current	I <sub>OUT</sub> max	BO1 to BO3	0 to 3.0	mA
Allowable power dissipation	Dilaray	Ta = 85°C: LM7001J (DIP16)	300	mW
	Pd max	Ta = 85°C: LM7001JM (MFP20)	180	mW
Operating temperature	Topr		-40 to +85	°C
Storage temperature	Tstg		-55 to +125	°C

# Allowable Operating Ranges at Ta=-40 to $+85^{\circ}C,\,V_{SS}$ = 0 V

Parameter	Symbol	Conditions	Ratings	Unit
Supply veltage	V <sub>DD</sub> 1	V <sub>DD</sub> 1, PLL circuit operating	4.5 to 6.5	V
Supply voltage	V <sub>DD</sub> 2	V <sub>DD</sub> 2, crystal oscillator time base	3.5 to 6.5	V
Input high-level voltage	VIH	CE, CL, DATA	2.2 to 6.5	V
Input low-level voltage	VIL	CE, CL, DATA	0 to 0.7	V
Output valtage	V <sub>OUT</sub> 1	SYC	0 to 6.5	V
Output voltage	V <sub>OUT</sub> 2	BO1 to BO3	0 to 13	V
Output current	I <sub>OUT</sub>	$\overline{\text{BO1}}$ to $\overline{\text{BO3}}$ , $V_{\text{DD}}$ = 4.5 to 6.5 V	0 to 3.0	mA
	f <sub>IN</sub> 1	XIN, sine wave, capacitor coupled	1.0 to 7.2 typ to 8.0	MHz
Input frequency	f <sub>IN</sub> 2	FMIN, sine wave, capacitor coupled*1, s*3 = 1	45 to 130	MHz
input noquonoy	f <sub>IN</sub> 3	FMIN, sine wave, capacitor coupled*2, s*3 = 1	5 to 30	MHz
	f <sub>IN</sub> 4	AMIN, sine wave, capacitor coupled, $s^{*3} = 0$	0.5 to 10	MHz
Crystal element for guaranteed oscillation	Xtal	XIN to XOUT, CI $\leq$ 30 $\Omega$	5.0 to 7.2 typ to 8.0	MHz
	V <sub>IN</sub> 1	XIN, sine wave, capacitor coupled	0.5 to 1.5	Vrms
Input amplitude	V <sub>IN</sub> 2	FMIN, sine wave, capacitor coupled	0.1 to 1.5	Vrms
	V <sub>IN</sub> 3	AMIN, sine wave, capacitor coupled	0.1 to 1.5	Vrms

Note: 1. f<sub>ref</sub> = 25, 50, or 100 kHz

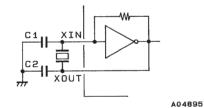
2. f<sub>ref</sub> = Reference frequencies other than those for \*1.
3. "s" refers to the control bit in the serial data.

Parameter	Symbol	Conditions	min	typ	max	Unit
	R <sub>f1</sub>	XIN		1.0		MΩ
Built-in feedback resistance	R <sub>f2</sub>	FMIN		500		kΩ
	R <sub>f3</sub>	AMIN		500		kΩ
Input high-level current	IIH	CE, CL, DATA: V <sub>IN</sub> = 6.5 V			5.0	μA
Input low-level current	Ι <sub>ΙL</sub>	CE, CL, DATA: V <sub>IN</sub> = 0 V			5.0	μA
	V <sub>OL</sub> 1	FMIN, AMIN: I <sub>OUT</sub> = 0.5 mA			3.5	V
	V <sub>OL</sub> 2	<u>SYC</u> : I <sub>OUT</sub> = 0.1 mA, *1	0.02		0.3	V
Output low-level voltage	V <sub>OL</sub> 3	$\overline{\text{BO1}}$ to $\overline{\text{BO3}}$ : I <sub>OUT</sub> = 2.0 mA			1.0	V
	V <sub>OL</sub> 4	P <sub>D</sub> 1, P <sub>D</sub> 2: I <sub>OUT</sub> = 0.1 mA			0.3	V
Output off leakage current	I <sub>OFF</sub> 1	$\overline{\text{SYC}}$ : V <sub>OUT</sub> = 6.5 V			5.0	μA
Output on leakage current	I <sub>OFF</sub> 2	$\overline{BO1}$ to $\overline{BO3}$ : V <sub>OUT</sub> = 13 V			3.0	μA
Output high-level voltage	V <sub>OH</sub>	$P_D1, P_D2: I_{OUT} = -0.1 \text{ mA}$	0.5 V <sub>DD</sub>			V
High-level 3-state off leakage current	IOFFH	$P_D 1, P_D 2: V_{OUT} = V_{DD}$		0.01	10.0	nA
Low-level 3-state off leakage current	I <sub>OFFL</sub>	P <sub>D</sub> 1, P <sub>D</sub> 2: V <sub>OUT</sub> = 0 V		0.01	10.0	nA
Current droin	I <sub>DD</sub> 1	V <sub>DD</sub> 1 + V <sub>DD</sub> 2: *2		25	40	mA
Current drain	I <sub>DD</sub> 2	V <sub>DD</sub> 2: PLL block stopped		2.0	3.5	mA
Input capacitance	CIN	FMIN	1	2	3	pF

#### **Electrical Characteristics in the Allowable Operating Ranges**

Note: 1. V<sub>DD</sub> = 3.5 to 6.5 V 2. With a 7.2 MHz crystal connected between XIN and XOUT, f<sub>IN</sub>2 = 130 MHz, V<sub>IN</sub>2 = 100 mVrms, other input pins at V<sub>SS</sub>, output pins open.

#### **Oscillator Circuit Example**

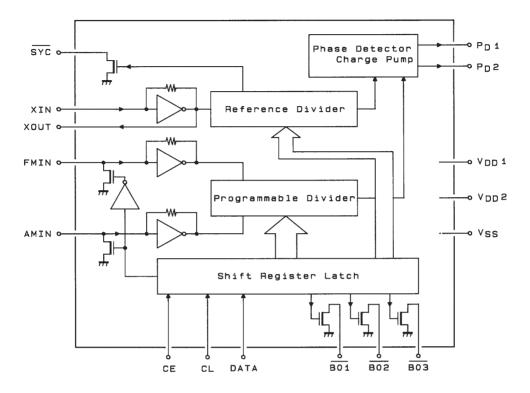


Kinseki, Ltd. HC43/U: 2114-84521 (1): CL = 10 pF, C1 = 15 (10 to 22) pF, C2 = 15 pF HC43/U: 2114-84521 (2): CL = 16 pF, C1 = 22 (15 to 33) pF, C2 = 33 pF

Nihon Denpa Kogyou, Ltd. NR-18: LM-X-0701: CL = 10 pF, C1 = 15 pF, C2 = 15 pF

Since the circuit constants in the crystal oscillator circuit depend on the crystal element used and the printed circuit board pattern, we recommend consulting with the manufacturer of the crystal element concerning this circuit.

# Equivalent Circuit Block Diagram



# **Pin Functions**

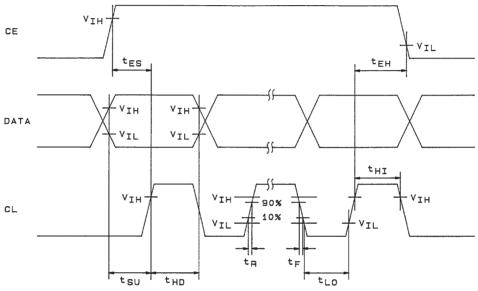
Symbol	Description
SYC	Controller clock (400 kHz)
XIN, XOUT	Crystal oscillator (7.2 MHz)
FMIN, AMIN	Local oscillator signal input
CE, CL, DATA	Data input
BO1 to BO3	Band data output. BO1 can be used as a time base output (8 Hz).
V <sub>DD</sub> 1, V <sub>DD</sub> 2, V <sub>SS</sub>	Power supply (Apply power to both $V_{DD}$ 1 and $V_{DD}$ 2 when the PLL circuit is operating. $V_{DD}$ 2 is the crystal oscillator and time base power supply. Internal data cannot be maintained on $V_{DD}$ 2 only.)
P <sub>D</sub> 1, P <sub>D</sub> 2	Charge pump output

# **Data Input Timing**

 $V_{IH}$  = 2.2 to 6.5 V,  $V_{IL}$  = 0 to 0.7 V, Xtal = 5.00 to 7.20 (typ) to 8.00 MHz

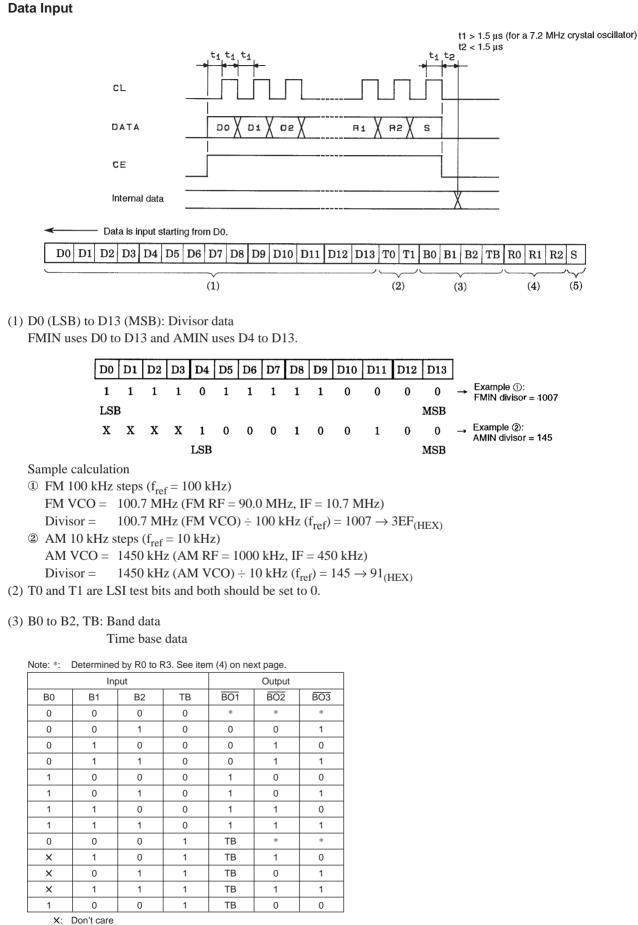
Data acquisition: On the CL rising edge \_\_\_\_\_

Note: Data transfers must be started only after the crystal oscillator is operating normally, i.e., after a proper input signal has been supplied to XIN.



AC	48	96	\$

Parameter	Symbol	Xtal: 7.20 MHz	Xtal: for frequencies other than 7.2 MHz	Example: XIN = 2.048 MHz
Enable setup time	t <sub>ES</sub>	At least 1.5 µs	At least $\left[\frac{1 \times 8}{f \text{ Xtal}}\right] \times 1.35$	At least 5.27 µs
Enable hold time	t <sub>EH</sub>	At least 1.5 µs	At least $\left[\frac{1 \times 8}{f \text{ Xtal}}\right] \times 1.35$	At least 5.27 µs
Data setup time	t <sub>SU</sub>	At least 1.5 µs	At least $\left[\frac{1 \times 8}{f \text{ Xtal}}\right] \times 1.35$	At least 5.27 µs
Data hold time	t <sub>HD</sub>	At least 1.5 µs	At least $\left[\frac{1 \times 8}{f \text{ Xtal}}\right] \times 1.35$	At least 5.27 µs
Clock low-level time	t <sub>LO</sub>	At least 1.5 µs	At least $\left[\frac{1 \times 8}{f \text{ Xtal}}\right] \times 1.35$	At least 5.27 µs
Clock high-level time	t <sub>HI</sub>	At least 1.5 µs	At least $\left[\frac{1 \times 8}{f \text{ Xtal}}\right] \times 1.35$	At least 5.27 µs
Rise time	t <sub>R</sub>	Up to 1 µs	Up to 1 µs	Up to 1 µs
Fall time	t <sub>F</sub>	Up to 1 µs	Up to 1 µs	Up to 1 µs



#### (4) R0 to R2: Reference frequency data

						-
R0	R1	R2	f <sub>ref</sub> [kHz]	BO1	BO2	BO3
0	0	0	100	1	1	0
0	0	1	50	1	1	0
0	1	0	25	1	1	0
0	1	1	5	0	0	1
1	0	0	10	1	0	1
1	0	1	9	1	0	1
1	1	0	1	0	1	1
1	1	1	5	0	0	1

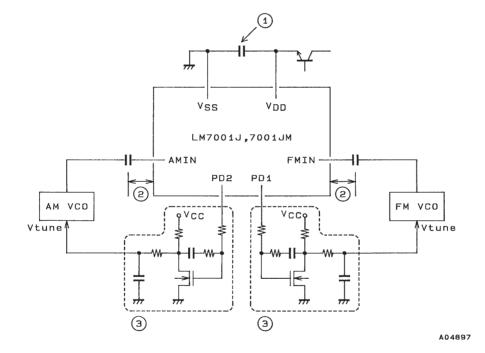
Note: The values listed for  $\overline{BO1}$ ,  $\overline{BO2}$ , and  $\overline{BO3}$  are for the case when the B0 to B2 data is set to all zeros.

(5) S: Divider selection data

1: FMIN, 0: AMIN

#### Notes on PLL IC Usage

1. PLL IC printed circuit board patterns



#### ① Power supply pins

A capacitor must be inserted between the  $V_{DD}$  and  $V_{SS}$  power supply pins for noise exclusion. This capacitor must be located as close as possible to these pins.

2 FMIN and AMIN pins

The coupling capacitors must be located as close as possible to these pins.

③ PD pins, low-pass filter

Since those are high-impedance pins, they are susceptible to noise. Therefore, the pattern should be kept as short as possible and the area around this circuit should be covered by the ground pattern.

2. Initial states of the output ports ( $\overline{BO1}$  to  $\overline{BO3}$ )

The initial states of the output ports after power is applied are undefined until data has been transferred. In particular, it is possible for the  $\overline{BO1}$  and  $\overline{BO3}$  pins to output the internal clock, so data must be transferred as soon as possible.

However, note that the LSI cannot accept data until the crystal oscillator is operating normally.

3. VCO

The VCO circuit is designed so that it does not stop oscillating even if the control voltage (Vtune) becomes 0 V. (This is because the PLL circuit could become deadlocked if the VCO stopped.)

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